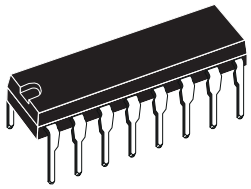
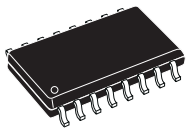
TDA7273

SINGLE CHIP STEREO CASSETTE PLAYBACK SYSTEM

- WIDE OPERATING SUPPLY VOLTAGE (1.8V to 7V)
- INPUT COUPLING WITHOUT CAPACITORS
- BUILT-IN DC STEREO VOLUME CONTROL
- BUILT-IN RIPPLE FILTERS
- LOW QUIESCENT CURRENT
- NO EXTERNAL BOUCHEROT CELL
- MAX OUTPUT CURRENT 70mA PEAK





DIP16 **SO16**

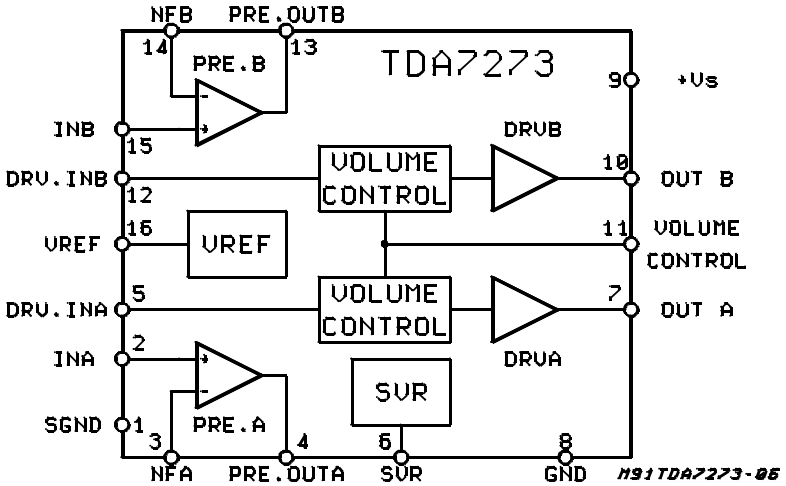
ORDERING NUMBERS:

TDA7273 TDA7273D

DESCRIPTION

The TDA7273 is a monolithic integrated circuit designed for portable cassette players market.
It comprises preamplifiers, DC volume control, and headphone drivers.

BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Test Conditions	Unit
V_S	Supply Voltage	9	V
I_o	Output Current (max)	70	mA
T_{op}	Operating Temperature Range	-20 to 70	°C
T_{stg}, T_j	Storage & Junction Temperature Range	-40 to +150	°C

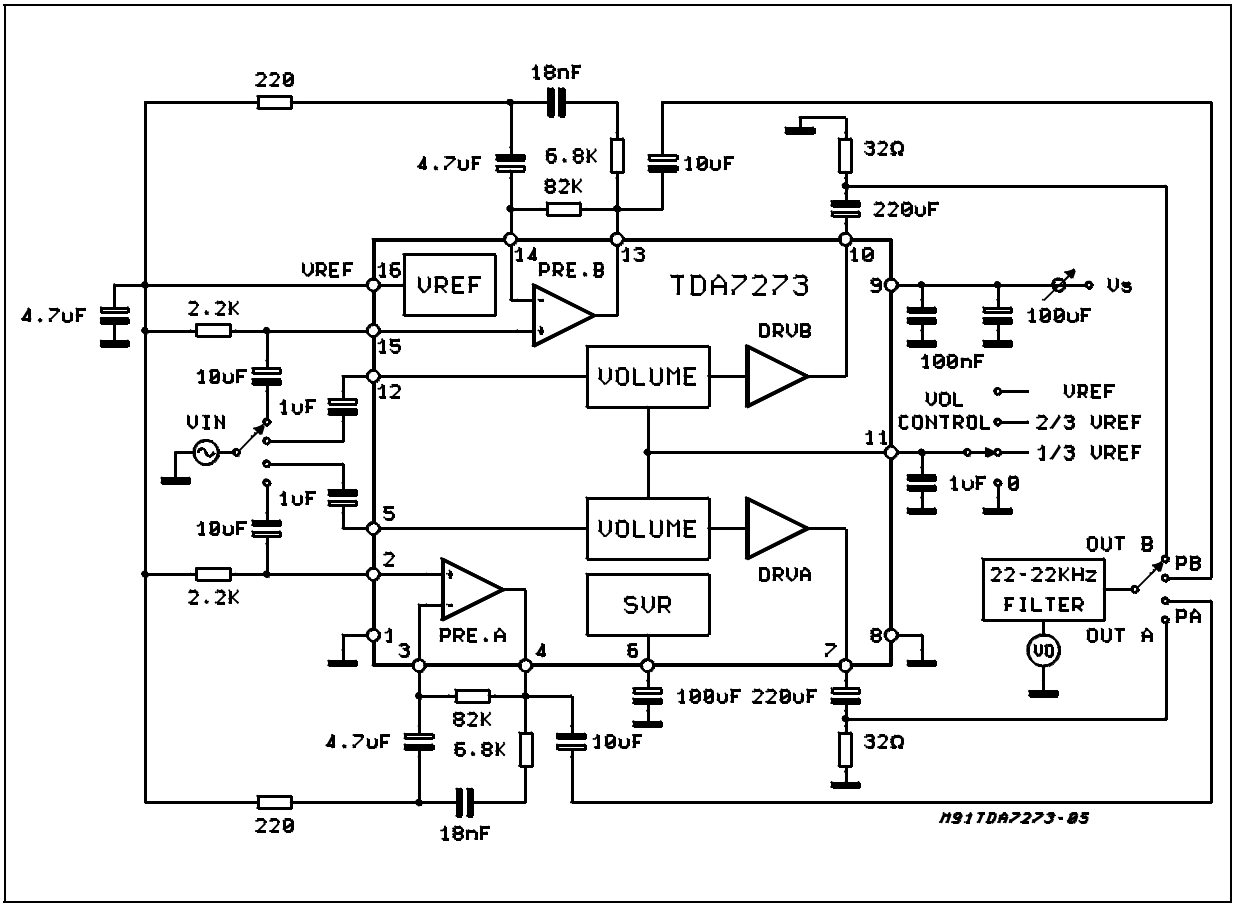
THERMAL DATA

Symbol	Description		DIP-16	SO-16	Unit
$R_{thj\text{-}amb}$	Thermal Resistance Junction-ambient	Max	100	200	°C/W

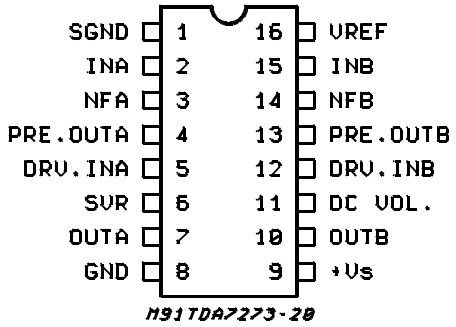
DC CHARACTERISTICS: T_{amb} = 25°C; V_S = 3V; R_L = 10KΩ (Preamplifier), R_L = 32Ω (Headphone); V_{IN} = 0; V_{OL} control = V_{ref}

Terminal No	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16
Terminal Voltage (V)	0	1.5	1.5	1.5	1.5	2.7	1.5	0	3	1.5	1.5	1.5	1.5	1.5	1.5	1.5

TEST CIRCUIT



PIN CONNECTION (Top view)



ELECTRICAL CHARACTERISTICS (T_{amb} = 25°C, V_S = 3V, f = 1KHz, R_L = 32Ω Vol. control = 2/3V_{ref} unless otherwise specified)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
V_S	Supply Voltage		1.8		7	V
I_d	Quiescent Current			14	20	mA
Vref	Reference Voltage		1.3	1.49	1.7	V
PREAMPLIFIER SECTION						
G_{VO}	Open Loop Gain			70		dB
G_V	Close Loop Gain		30	33	35	dB
V_o	Output Voltage	THD = 1%	600	850		mV
I_b	Bias Current			3		µA
THD	Total Harmonic Distortion	V_o = 330mVrms		0.05	0.25	%
C_t	Cross Talk	Rg = 2.2KΩ; V_o = 330mVrms		74		dB
E_N	Output Noise	Rg = 2.2KΩ; BW = 22Hz to 22KHz		100		µV
SVR	Ripple Rejection	R_g = 2.2KΩ V_R = 100mVrms f = 100Hz; C_{SVR} = 100µF	40	50		dB
HEADPHONE DRIVER						
$V_{o(DC)}$	DC Output Voltage			1.50		V
P_o	Output Power	THD = 10%;	15	30		mW
P_o	Transient Output Power	THD = 10% RL = 16Ω		50		mW
G_V	Close Loop Gain	P_o = 5mW	28	31	34	dB
THD	Total Harmonic Distortion	P_o = 5mW		0.2	1	%
C_t	Cross Talk	Rg = 10KΩ; P_o = 5mW	40	50		dB
SVR	Ripple Rejection	V_r = 100mVrms, f = 100Hz Vol. control = 1/3V_{ref} C_{SVR} = 100µF; R_g =600Ω		47		dB
	Volume Control Range		66	75		dB

Figure 1: Application Circuit

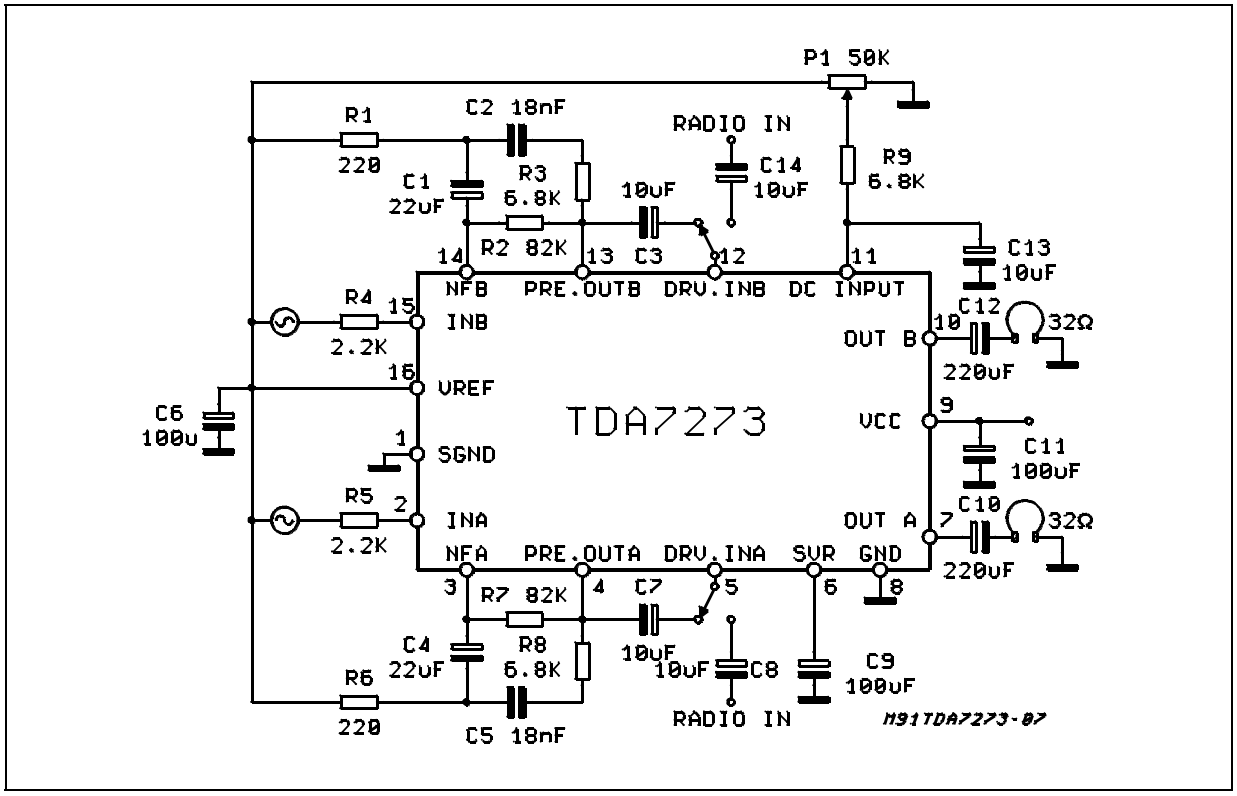


Figure 2: P.C. Board and Component Layout of the Circuit of Figure 1 (1:1 scale)

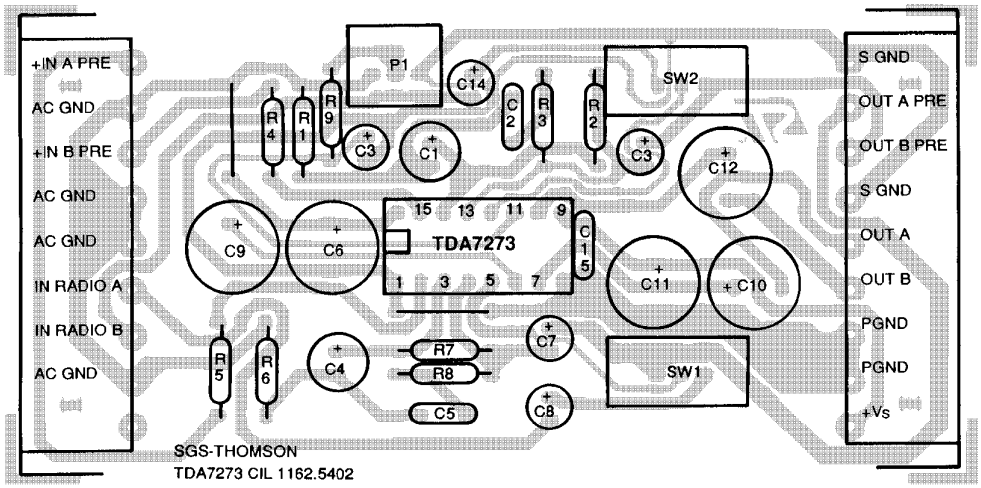


Figure 3: Supply Current vs. Supply Voltage (Preamplifier + Driver)

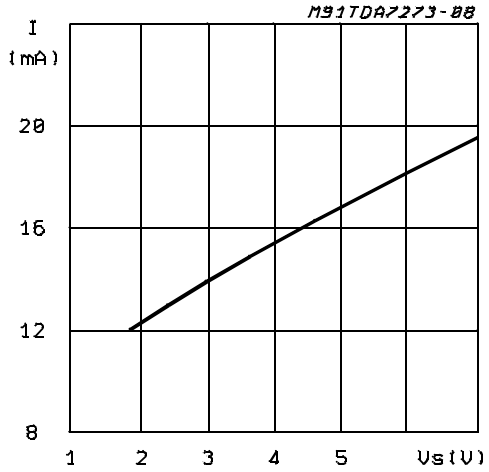


Figure 4: V_{ref}, vs. Supply Voltage (pin 16)

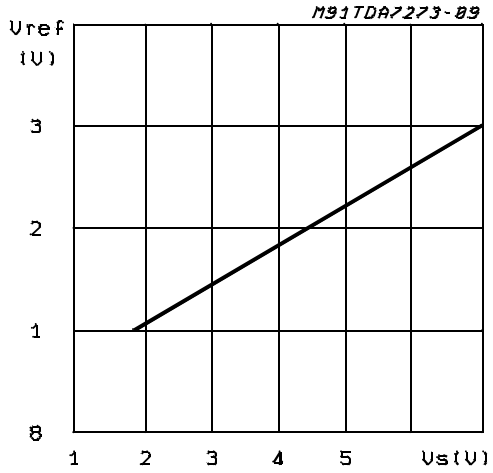


Figure 5: Closed Loop Gain vs. Frequency (V_S = 3V) (PREAMPLIFIER)

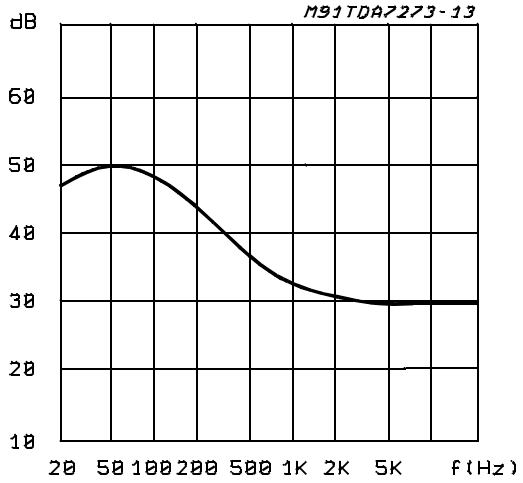


Figure 6: THD vs. Frequency (V_S = 3V, V_o =330mVrms, R_L = 10KΩ) (PREAMPLIFIER)

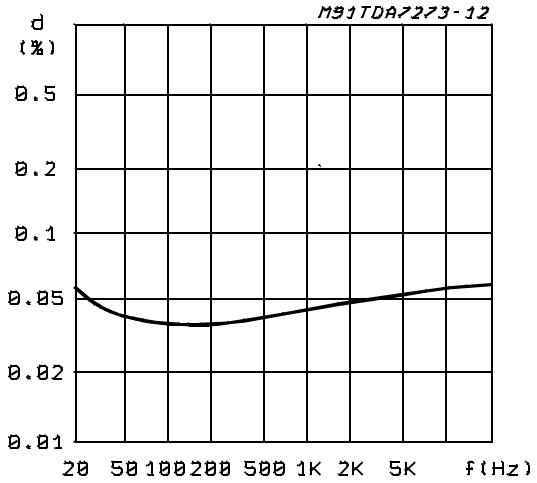


Figure 7: SVR vs. Frequency (PREAMPLIFIER)

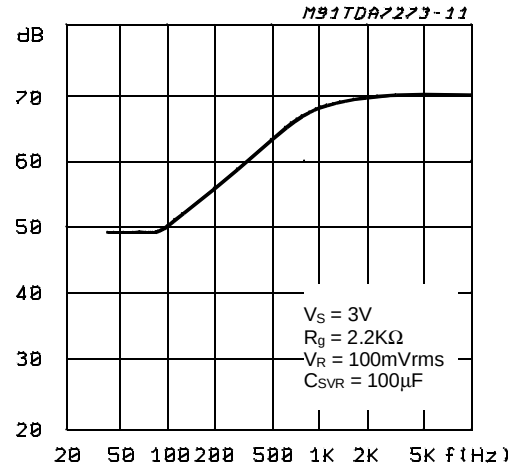


Figure 8: Quiescent Output Voltage vs. Supply Voltage (DRIVER)

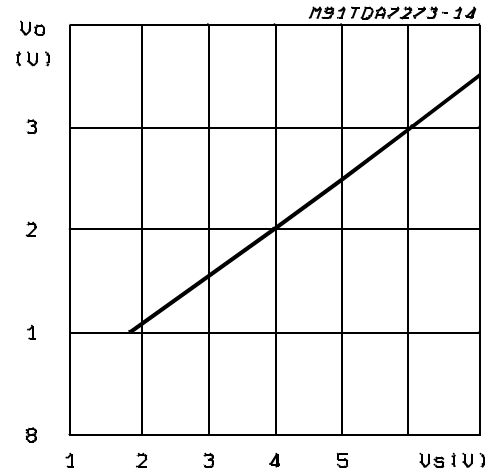


Figure 9: Closed Loop Gain vs Frequency (V_S = 3V, R_L = 32Ω) (DRIVER)

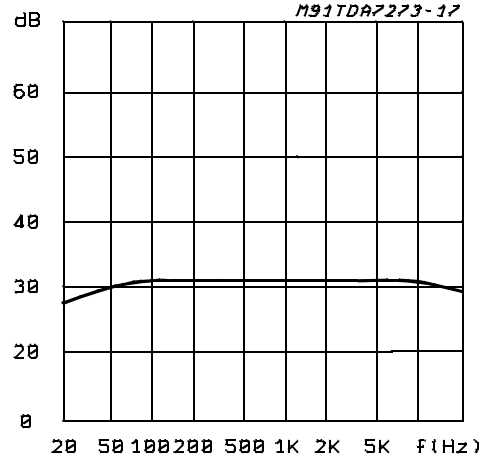


Figure 10: Output Power vs. Supply Voltage (Vol = 2/3V_{ref}, R_L = 32Ω, THD = 10%, f = 1KHz) (DRIVER)

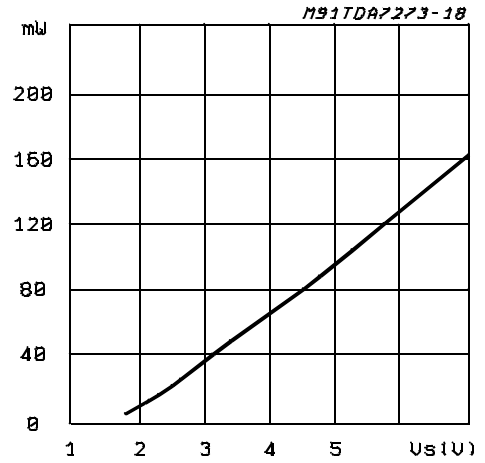


Figure 11: THD vs. Output Power (V_o = 2/3V_{ref}, V_S = 3V, R_L = 32Ω, f = 1KHz) (DRIVER)

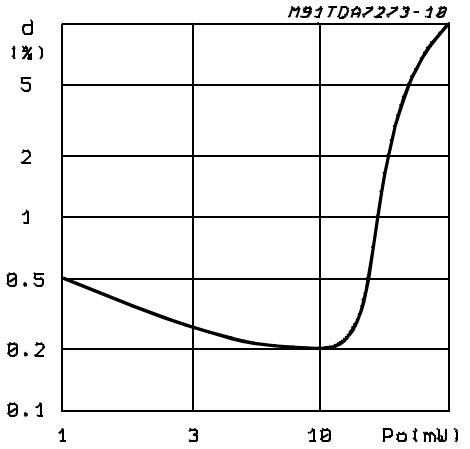


Figure 12: THD vs. Frequency (P_o = 5mW, V_S = 3V R_L = 32Ω) (DRIVER)

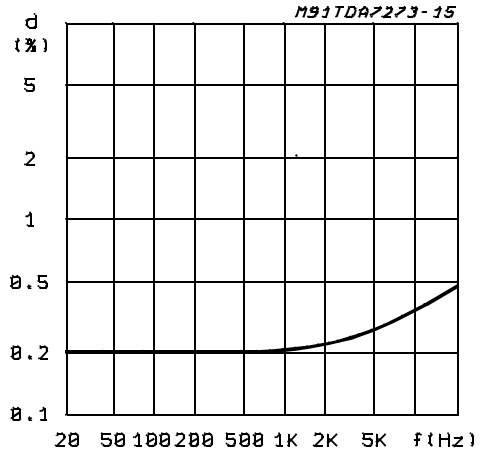


Figure 13: SVR vs. Frequency V_S = 3V (R_L = 32Ω, V_r = 100Vrms R_g = 600Ω, C_{SVR} = 100mV) (DRIVER)

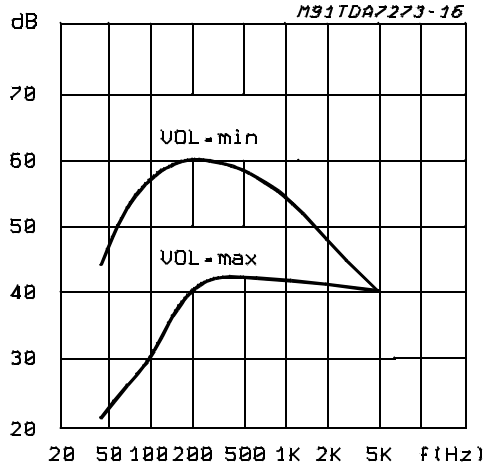
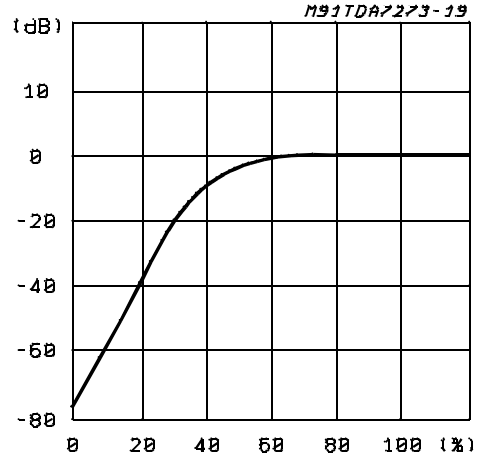
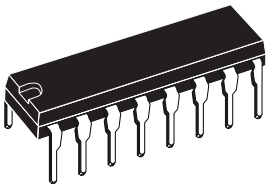


Figure 14: Volume Control (0dB = 10mW, V_S = 3V R_{vol} = 50KΩ, R_L = 32Ω, f = 1KHz) vs. Volume Setting (DRIVER)

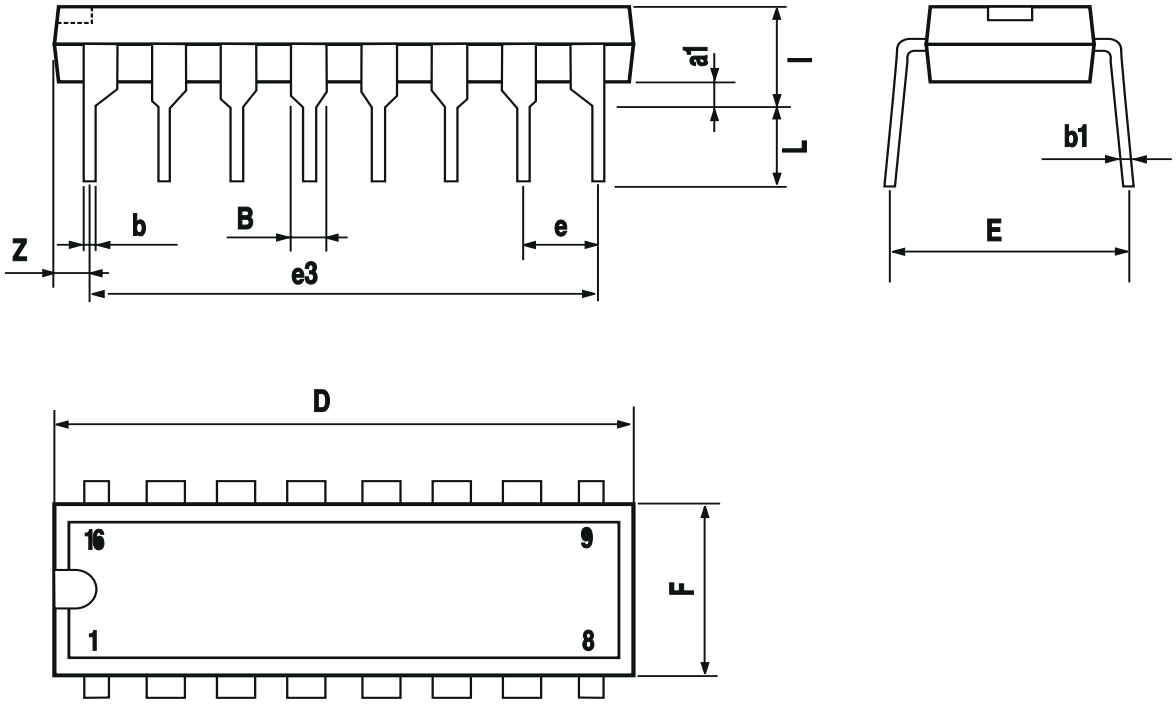


DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
B	0.77		1.65	0.030		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		17.78			0.700	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z			1.27			0.050

OUTLINE AND MECHANICAL DATA

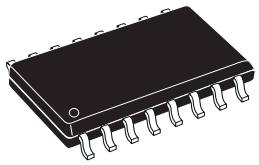


DIP16

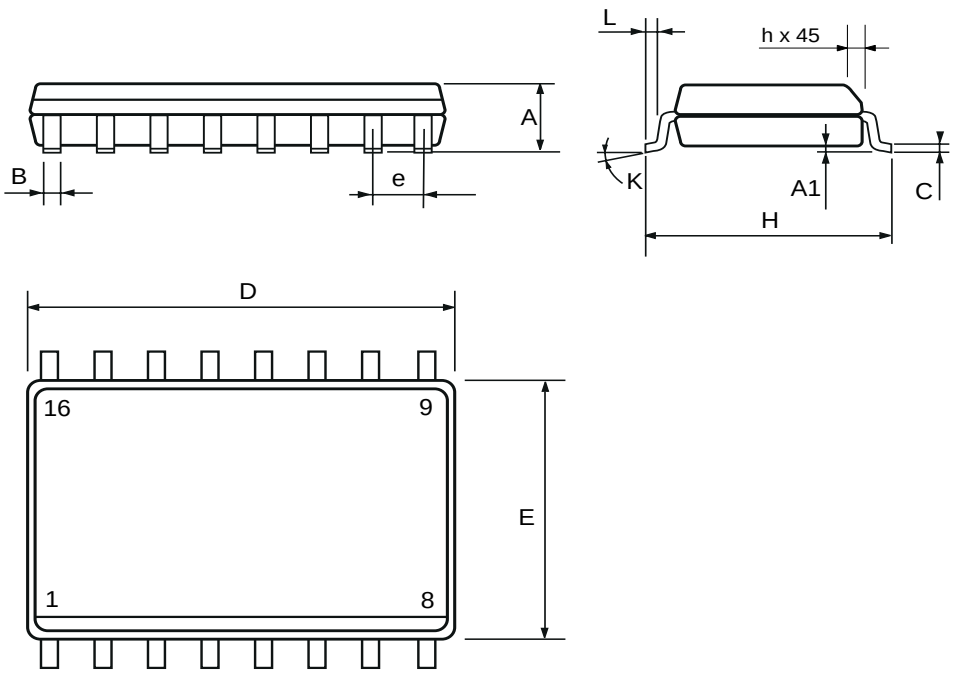


DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	2.35		2.65	0.093		0.104
A1	0.1		0.3	0.004		0.012
B	0.33		0.51	0.013		0.020
C	0.23		0.32	0.009		0.013
D	10.1		10.5	0.398		0.413
E	7.4		7.6	0.291		0.299
e		1.27			0.050	
H	10		10.65	0.394		0.419
h	0.25		0.75	0.010		0.030
L	0.4		1.27	0.016		0.050
K	0˚ (min.)8˚ (max.)					

OUTLINE AND MECHANICAL DATA



SO16 Wide



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